US Department of Defense in the clearing and sanitizing standard **DoD 5220.22-M** recommends the approach *"Overwrite all addressable locations with a character, its complement, then a random character and verify"* (see table with comments) for clearing and sanitizing information on a writable media.

To conform this security standard Active@ Disk Wiper implemented this approach, i.e. triple data overwriting for the destruction of remains of sensitive data.

US Department of Defense 5220.22-M Clearing and Sanitization Matrix

| Media | Clear | Sanitize |
|--|-------------------|-----------------------|
| Magnetic Tape1 | | |
| Туре І | a or b | a, b, or m |
| Type II | a or b | b or m |
| Туре III | a or b | m |
| Magnetic Disk | | |
| Bernoullis | a, b, or c | m |
| Floppies | a, b, or c | m |
| Non-Removable Rigid Disk | С | a, b, d , or m |
| Removabel Rigid Disk | a, b, or c | a, b, d , or m |
| Optical Disk | | |
| Read Many, Write Many | С | m |
| Read Only | | m, n |
| Write Once, Read Many (Worm) | | m, n |
| Memory | | |
| Dynamic Random Access memory (DRAM) | c or g | c, g, or m |
| Electronically Alterable PROM (EAPROM) | i | j or m |
| Electronically Erasabel PROM (EEPROM) | i | h or m |
| Erasable Programmable (ROM (EPROM) | k | I, then c, or m |
| Flash EPROM (FEPROM) | i | c then i, or m |
| Programmable ROM (PROM) | С | m |
| Magnetic Bubble Memory | С | a, b, c, or m |
| Magnetic Core Memory | С | a, b, e, or m |
| Magnetic Plated Wire | С | c and f, or m |
| Magnetic Resistive Memory | С | m |
| Nonvolatile RAM (NOVRAM) | c or g | c, g, or m |
| Read Only Memory ROM | | m |
| Static Random Access Memory (SRAM) | c or g | c and f, g, or m |
| Equipment | | |
| Cahtode Ray Tube (CRT) | g | q |
| Printers | | |
| Impact | g | p then g |
| Laser | g | o then g |

US Department of Defense 5220.22-M Clearing and Sanitization Matrix

- a. Degauss with a Type I degausser
- b. Degauss with a Type II degausser.
- c. Overwrite all addressable locations with a single character.

d. Overwrite all addressable locations with a character, its complement, then a random character and verify. THIS METHOD IS NOT APPROVED FOR SANITIZING MEDIA THAT CONTAINS TOP SECRET INFORMATION.

e. Overwrite all addressable locations with a character, its complement, then a random character.

- f. Each overwrite must reside in memory for a period longer than the classified data resided.
- g. Remove all power to include battery power.

h. Overwrite all locations with a random pattern, all locations with binary zeros, all locations with binary ones.

- i. Perform a full chip erase as per manufacturer's data sheets.
- j. Perform i above, then c above, a total of three times.
- k. Perform an ultraviolet erase according to manufacturer's recommendation.
- I. Perform k above, but increase time by a factor of three.
- m. Destroy Disintegrate, incinerate, pulverize, shred, or melt.
- n. Destruction required only if classified information is contained.
- o. Run five pages of unclassified text (font test acceptable).
- p. Ribbons must be destroyed. Platens must be cleaned.

q. Inspect and/or test screen surface for evidence of burned-in information. If present, the cathode ray tube must be destroyed.